

V_R 1200V I_{F} 10A 34nC

Q_{C}

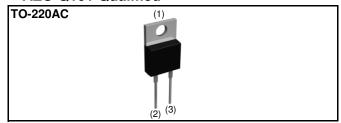
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

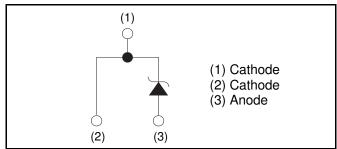
Construction

Silicon carbide epitaxial planer schottky diode

●AEC-Q101 Qualified



●Inner circuit



Packaging specifications

Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS210KG

● Absolute maximum ratings (Ti = 25°C)

Parameter	Symbol	Value	Unit	
Reverse voltage (repetitive peak)	V_{RM}	1200	V	
Reverse voltage (DC)	V _R	1200	V	
Continuous forward current	I _F	10* ¹	Α	
		45* ²	Α	
Surge no repetitive forward current	I _{FSM}	190* ³	А	
		45* ²		
Repetitive peak forward current	I _{FRM}	46* ⁵	А	
Total power disspation	P _D	150* ⁶	W	
Junction temperature	Tj	175	°C	
Range of storage temperature	Tstg	−55 to +175	°C	

^{*1} Tc=146°C *2 PW=8.3ms sinusoidal,Tj=25°C *3 PW=10µs square,Tj=25°C

^{*4} Pw=8.3ms sinusoidal, Tj=150°C, *5 Tc=100°C, Tj=150°C, Duty cycle=10% *6 Tc=25°C

●Electrical characteristics (Tj = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Farameter			Min.	Тур.	Max.	UIIIL
DC blocking voltage	V_{DC}	I _R =0.2mA	1200	-	-	V
	V _F	I _F =10A,Tj=25°C	-	1.4	1.6	V
Forward voltage		I _F =10A,Tj=150°C	-	1.8	-	V
		I _F =10A,Tj=175°C	-	1.9	-	V
	I _R	V _R =1200V,Tj=25°C	-	10	200	μΑ
Reverse current		V _R =1200V,Tj=150°C	-	80	-	μΑ
		V _R =1200V,Tj=175°C	-	130	-	μΑ
Total conscitones	С	V _R =1V,f=1MHz	-	550	-	pF
Total capacitance		V _R =800V,f=1MHz	-	42	-	pF
Total capacitive charge	Qc	V _R =800V,di/dt=500A/μs	-	34	-	nC
Switching time	tc	V _R =800V,di/dt=500A/μs	-	15	-	ns

Thermal characteristics

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Thermal resistance	Rth(j-c)	-	-	0.73	0.99	°C/W

• Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

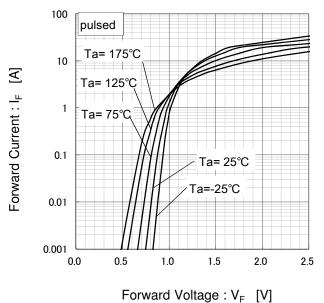
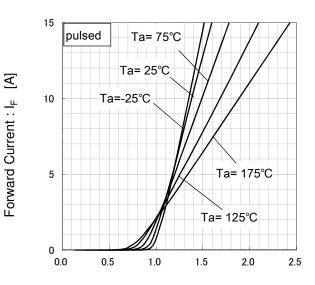


Fig.2 V_F - I_F Characteristics



Forward Voltage: V_F [V]

Fig.3 V_R - I_R Characteristics

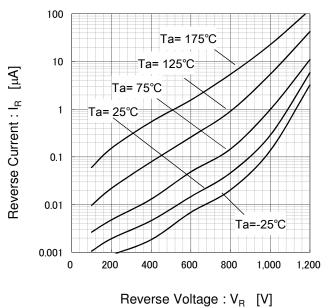
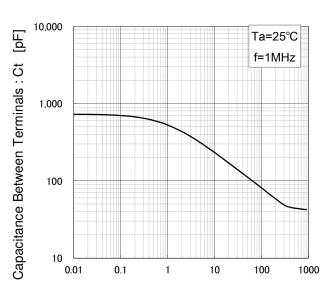


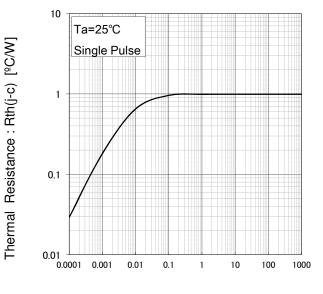
Fig.4 V_R-Ct Characteristics



V] Reverse Voltage : V_R [V]

• Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width



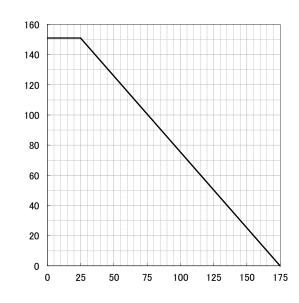
Pulse Width: Pw [s]

Fig.6 Power Dissipation

Power Dissipation [W]

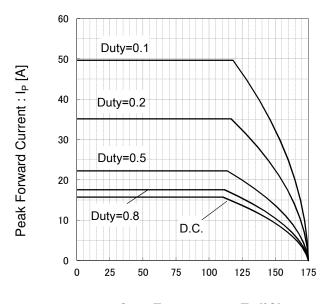
Power Dissipation [W]

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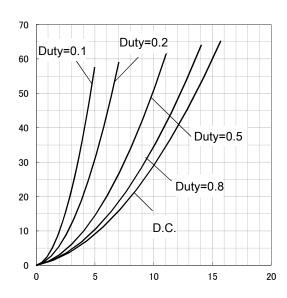
Case Temperature : Tc [ºC]

Fig.7 Derating Curve Ip-Tc



Case Temperature : Tc [ºC]

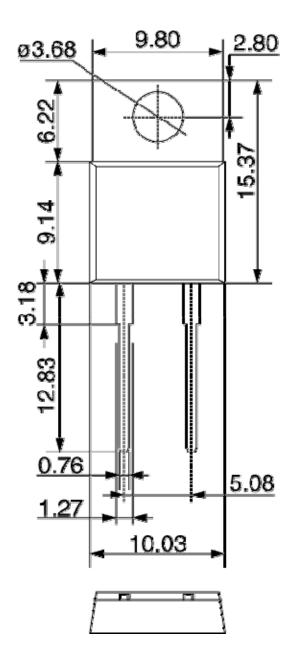
Fig.8 Io-Pf Characteristics

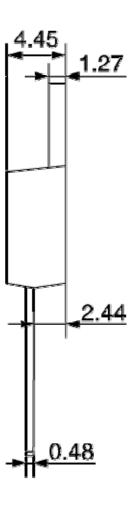


Average Rectified Forward Current : Io [A]

● **Dimensions** (Unit: mm)

TO-220AC





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